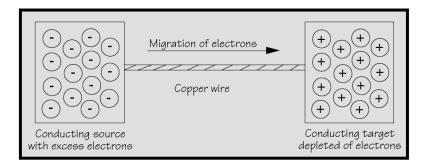


#### **Basic Concepts of Electricity**

- Voltage
- Current
- Resistance





#### **Electric Fields**

- An electric field applies a force to a charge
  - Force on positive charge is in direction of electric field, negative is opposite
- Charges move if they are mobile
- An electric field is produced by charges (positive and negative charges)
- Electric fields can be produced by time varying magnetic fields (generator, antenna radiation)

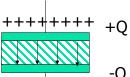


#### Voltage Difference

- Voltage difference is the difference in potential energy in an electric field
- E = V/d
- As you move closer to a positive charge the voltage increases

Capacitor (electric field constant between parallel plates)

Metal Dielectric Metal





3



#### Current

- An electric current is produced by the flow of electric charges
- Current = rate of charge movement
  - = amount of charge crossing a surface per unit time
- In conductors, current flow is due to electrons
- Conventional current is defined by the direction positive charges will flow
- Direction of electron flow is opposite to direction of conventional current



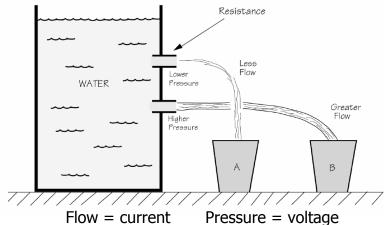
#### Resistance

- In materials electrons accelerate in an electric field
- Electrons lose energy when they hit atoms lost energy appears as heat and light
- The result is that electrons drift with constant velocity (superimposed on random thermal motion)
- Resistance is the ratio Voltage/current
   R = V/I

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# Voltage, Current, and Resistance





# **Material Conductivity**

- Conductors negligible resistance
- Insulators extremely large resistance
- Semiconductors some resistance
- Resistors are devices designed to have constant resistance across a range of voltages

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# **Resistor Combination**

#### Series resistance

R1 Parallel resistance

$$= \frac{1}{\sqrt{2}} = \frac$$

1/R = 1/R1 + 1/R2



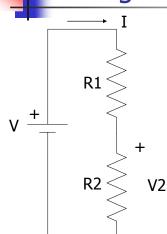
# Kirchoff's Voltage Law

- Kirchoff's voltage law (KVL)
  - The sum of voltage differences around any loop in a circuit equals 0
  - Equivalently, the voltage between two points is the same no matter what path is traversed

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#### Voltage Divider



$$V2 = VR1$$

$$R1 + R2$$

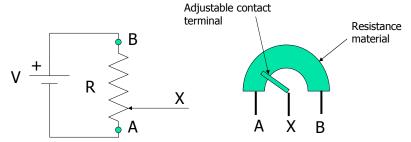
#### Solution:

Goal: Find V2 given V

- •Find V2 in terms of I
- •Current through R2 in terms of I
- Voltage across R1
- •Find voltage across R1 and R2 using two different methods



# Potentiometer (Variable Resistor)



VX = V \* Distance AX/Distance AB (linear potentiometer)

A trimpot is a small variable resistor mounted on a printed circuit board that can adjusted by a small screwdriver to make semi-permanent adjustments to a circuit

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### **Input Transducers**

- These are devices that produce electric signals in accordance with changes in some physical effect e.g. convert temperature, light level to a voltage level or resistance
- e.g. microphones, strain gauge, photodetectors, ion-selective membranes, thermistors
- Sometimes the definition of transducer is that of a device that converts non-electrical energy to electrical energy



# **Output Transducers**

 Devices which convert an electrical quantity into some other physical quantity or effect e.g. relay, loudspeaker, solenoid

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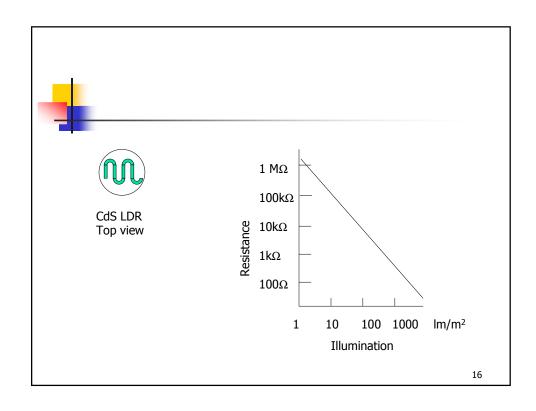
#### Light Dependent Resistors (LDRs)

- Devices whose resistance changes (usually decreases) with light striking it
- (also called photocells, photoconductors)
- Light striking a semiconducting material can provide sufficient energy to cause electrons to break away from atoms.
- Free electrons and holes can be created which causes resistance to be reduced



#### **LDRs**

- Typical materials used are Cadmium Sulphide (CdS), Cadmium Selenide (CdSe), Lead Sulphide
- With no illumination, resistance can be greater than  $1 \text{ M}\Omega$  (dark resistance).
- Resistance varies inversely proportional to light intensity.
- Reduces down to 10-100s ohms
- 100ms/10ms response time





- LDRs have a low energy gap
- Operate over a wide wavelengths (some, into infrared)
- Indium antimonide is good for IR.
   When cooled is very sensitive, used for thermal scanning of earth's surface

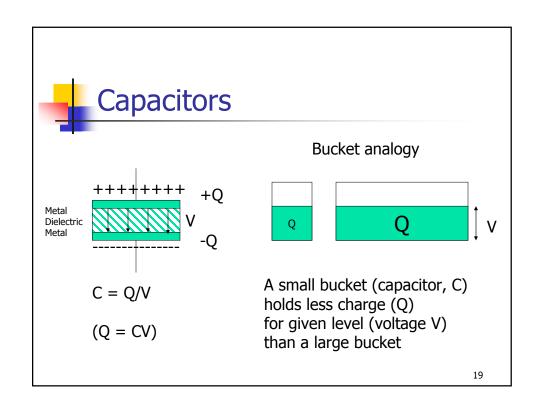
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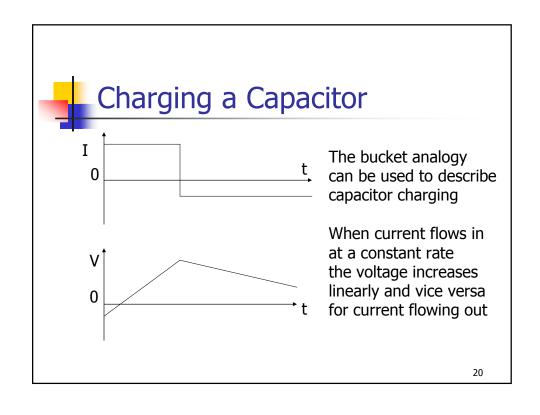


#### **Capacitors**

- A component constructed from two conductors separated by an insulating material (dielectric) that stores electric charge (+Q, -Q)
- As a consequence there is a voltage difference across the capacitor, V
- Capacitance = C = Q/V
- The dielectric material operates to reduce the electric field between the conductors and so allow more charge to be stored for a given voltage

8.



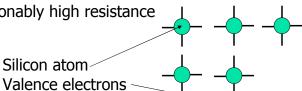




#### Semiconductors

- Silicon is used as an example (other semiconductors include Germanium, Gallium Arsenide, Gallium phosphide, indium arsenide, indium phosphide)
- Pure silicon (intrinsic semiconductor)
  - Four valance electrons
  - Crystalline structure
  - Reasonably high resistance

Silicon atom-





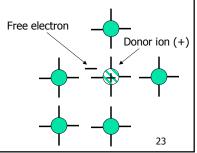
#### Electrons and holes

- Due to thermal energy some electrons in the valance shell become free
- Create:
  - One free electron +
  - One hole in the valence band that can be filled by electrons from the valance band in an adjacent silicon atom
- Current in silicon can flow due to both movement of electrons and holes



#### n-type silicon

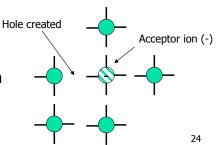
- Add donor impurities (e.g. Phosphorus, arsenic, indium) with 5 electrons in the valance band
- As only four electrons can bond with neighbouring silicon atoms one free electron is left
- Increases concentration of free electrons
- Reduces concentration of holes (due to increased chance of recombination)
- Resistance reduced





#### p-type silicon

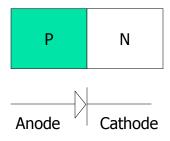
- p-type silicon is created by adding acceptor impurities which have three valance electrons (e.g. boron)
- This leaves an unbound valance electron in an adjacent silicon atom creating a hole
- Increases concentration of holes
- Reduces concentration of free electrons
- P-type silicon has lower resistance than pure silicon





#### **Diodes**

 If a piece of n-type silicon and p-type silicon are joined directly together a diode (di - electrode) device is created

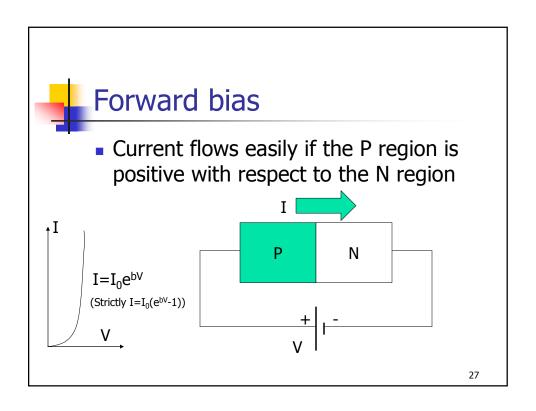


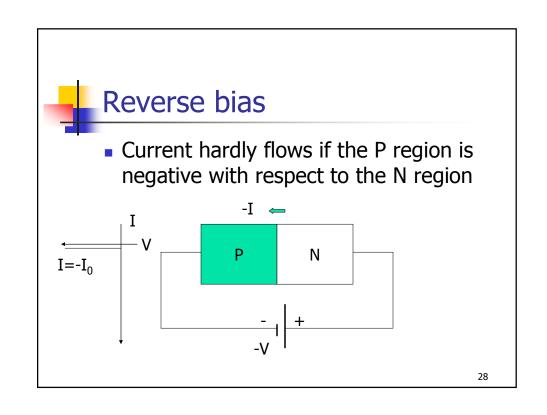
2.



# Macro-behaviour

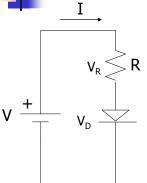
 A diode is a device that allows current flow easily in one direction easily and allows hardly any current flow in the opposite direction







#### Diode and resistor circuit



Currents and voltages determined by: (work backwards to find  $V_{\text{D}}$ )

- 1. V<sub>D</sub> related to I by diode equation
- 2. Current in resistor and diode equal
- 3.  $V_R = IR$
- 4. voltage across diode and voltage resistor add up to voltage source V

Short cut rule of thumb,  $V_D$  is approx 0.6-0.7 volts and  $V_R \approx V - 0.6$ 

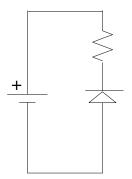
For LEDs  $V_{\text{D}}^{''}$  is about 1.8 - 4.0 V, depending on colour

Forward biased diode

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# Diode and resistor circuit



Assume no reverse-bias current flows (ideal case)

Therefore no voltage occurs across the resistor

Therefore the full supply voltage appears across the diode

Reverse biased diode



#### **LEDs**

- Light emitting diode
- When an electron moves down from the conduction band to the valence band it loses energy
- In silicon and germanium the energymomentum relationships mean that this energy is lost heat
- In gallium arsenide it produces a photon

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#### **LEDs**

- The light intensity is proportional to current
- Pure gallium arsenide produces infrared light
- GaAsP produces red or yellow light
- GaP produces red or green



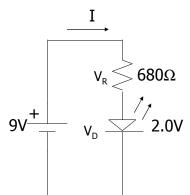
# Circuit design using LEDs

- LEDs behave just like normal diodes except that the forward bias voltages are greater (typically 1.8 - 4.0 V)
- A typical forward bias current of 10-20 mA is used.

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# Example



$$I = 9 - 2.0$$
  
 $680$   
= 10.29 mA



# Introduction to AVR

#### Atmel AVR Microcontroller

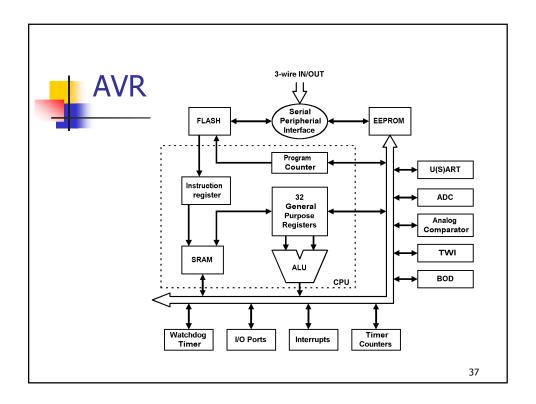
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# **AVR Key Features**

- High Performance 8-Bit MCU
- RISC Architecture
  - 32 Registers
  - 2-Address Instructions
  - Single Cycle Execution
- Low Power
- Large linear address spaces
- Efficient C Language Code Density
- On-chip in-system programmable memories

RISC Performance with CISC Code Density





# ATmega16(L)

- 40/44 pin packages
- 16 KBytes ISP Flash, Self Programmable
- 512 Bytes ISP EEPROM
- 1 KBytes SRAM
- Full Duplex UART
- SPI Serial Interface
- TWI Serial Interface
- 8- and 16-bits Timer/Counters with PWM
- 2 External Interrupts
- 10-bit ADC with 8 Multiplexed Inputs
- RTC with Separate 32 kHz Oscillator
- Analog Comparator
- JTAG Interface with On-Chip Debugger



# Typical Applications, ATmega16(L)

- Smart Battery
- Advanced Battery Charger
- Power Meter
- Temperature Logger
- Voltage Logger
- Tension Control
- Touch Screen Sensor
- Metering Applications
- UPS
- 3 Phase Motor Controller
- Industrial Control
- Power Management

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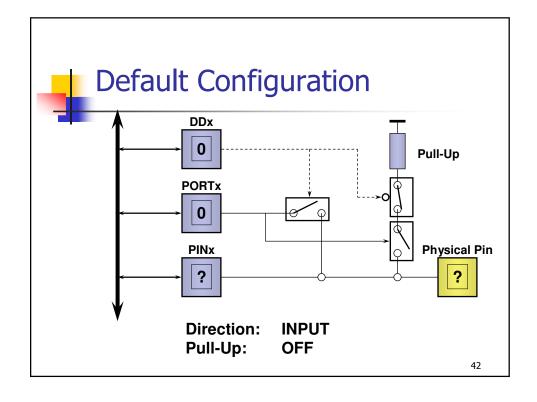
# I/O Ports General Features

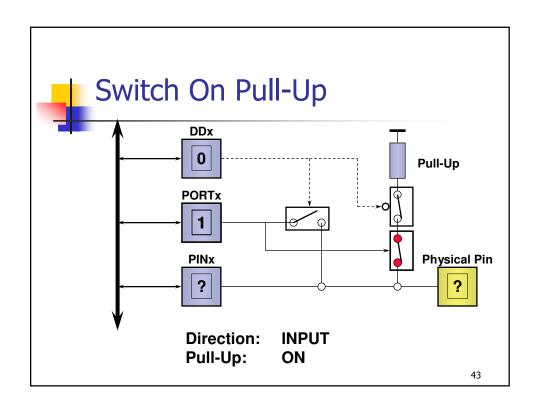
- Push-Pull Drivers
- High Current Drive (sinks up to 40 mA)
- Pin-wise Controlled Pull-Up Resistors
- Pin-wise Controlled Data Direction
- Fully Synchronized Inputs
- Three Control/Status Bits per Bit/Pin
- Real Read-Modify-Write

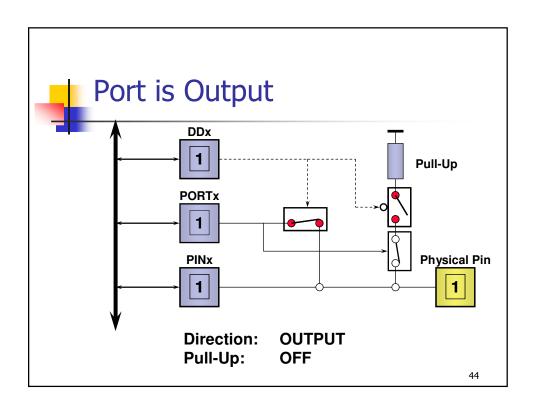


# 3 Control/Status Bits per Pin

- DDx Data Direction Control Bit
- PORTx Output Data or Pull-Up Control Bit
- PINx Pin Level Bit









#### General T/C Features

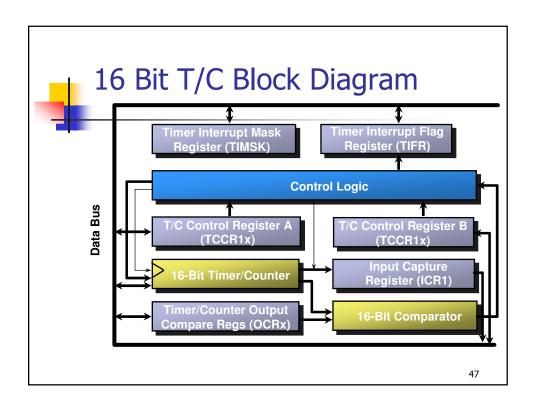
- Various Clock Prescaling Options
- Can Run at Undivided XTAL Frequency (High Resolution)
- Can be Set to Any Value at Any Time
- Can be Clocked Externally by Signals with Transition Periods down to XTAL/2
- Can be Clocked Externally on both Rising and Falling Edge
- The features vary from device to device, see datasheets for details

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#### 16 Bit Timer/Counter

- Prescaler
- Overflow Interrupt
- Output Compare Function with Interrupt
- Input Capture with Interrupt and Noise Cancler
- PWM





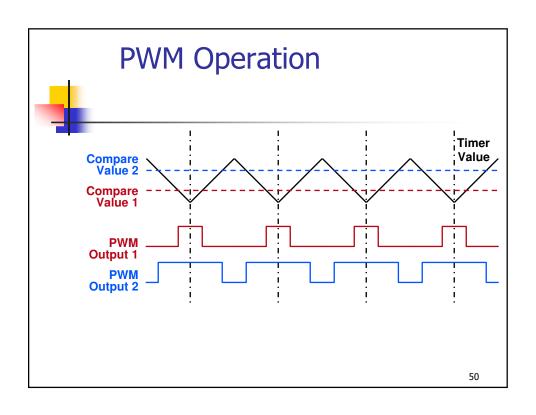
# **Output Compare Features**

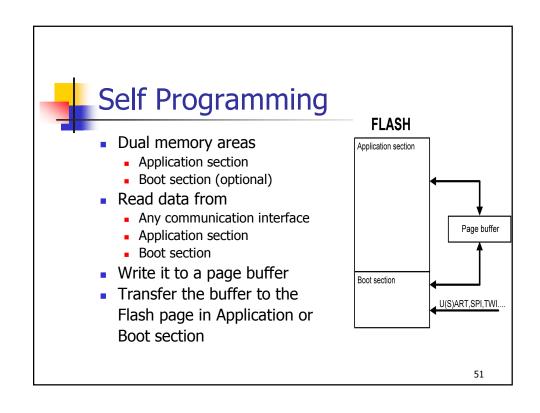
- Compare match can control an external pin (Rise, Fall or Toggle) even if the Interrupt is disabled.
- As an option, the timer can be automatically cleared when a compare match occurs.

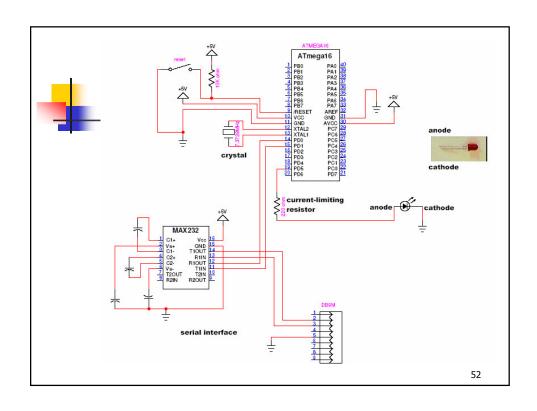


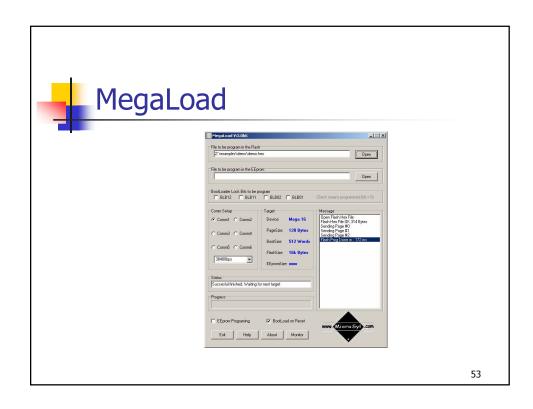
#### **PWM Features**

- Selectable 8, 9 or 10-Bit Resolution.
- Frequency @ 10 MHz (8-bit): 19 KHz
- Centered Pulses
- Glitch-Free Pulse Width Change
- Selectable Polarity











# AVR websites and mail

- ATMEL website www.atmel.com
  - Datasheets
  - Application Notes
  - FAQ
- Unofficial AVR websites

www.avrfreaks.net www.avr-forum.com